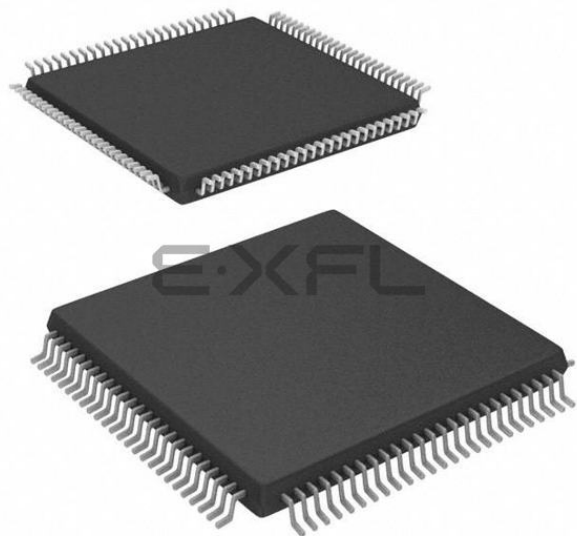




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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	216
Number of Logic Elements/Cells	972
Total RAM Bits	24576
Number of I/O	60
Number of Gates	30000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc2s30-5vqg100i

Spartan-II Product Availability

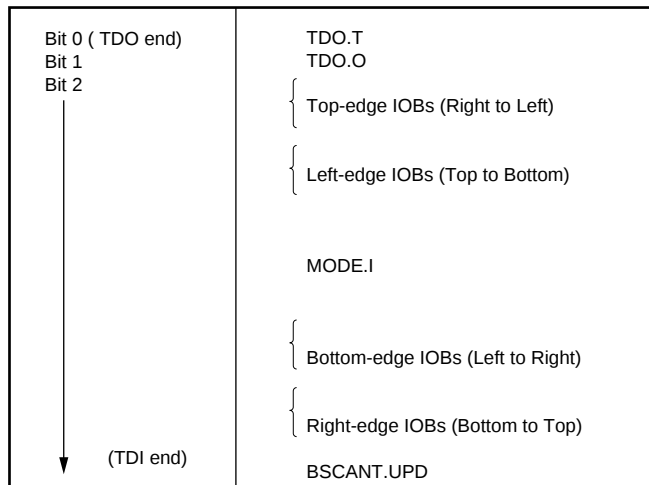
Table 2 shows the maximum user I/Os available on the device and the number of user I/Os available for each device/package combination. The four global clock pins are usable as additional user I/Os when not used as a global clock pin. These pins are not included in user I/O counts.

Table 2: Spartan-II FPGA User I/O Chart⁽¹⁾

Device	Maximum User I/O	Available User I/O According to Package Type					
		VQ100 VQG100	TQ144 TQG144	CS144 CSG144	PQ208 PQG208	FG256 FGG256	FG456 FGG456
XC2S15	86	60	86	(Note 2)	-	-	-
XC2S30	92	60	92	92	(Note 2)	-	-
XC2S50	176	-	92	-	140	176	-
XC2S100	176	-	92	-	140	176	(Note 2)
XC2S150	260	-	-	-	140	176	260
XC2S200	284	-	-	-	140	176	284

Notes:

1. All user I/O counts do not include the four global clock/user input pins.
2. Discontinued by [PDN2004-01](#).



DS001_10_032300

Figure 10: Boundary Scan Bit Sequence

Development System

Spartan-II FPGAs are supported by the Xilinx ISE® development tools. The basic methodology for Spartan-II FPGA design consists of three interrelated steps: design entry, implementation, and verification. Industry-standard tools are used for design entry and simulation, while Xilinx provides proprietary architecture-specific tools for implementation.

The Xilinx development system is integrated under a single graphical interface, providing designers with a common user interface regardless of their choice of entry and verification tools. The software simplifies the selection of implementation options with pull-down menus and on-line help.

For HDL design entry, the Xilinx FPGA development system provides interfaces to several synthesis design environments.

A standard interface-file specification, Electronic Design Interchange Format (EDIF), simplifies file transfers into and out of the development system.

Spartan-II FPGAs supported by a unified library of standard functions. This library contains over 400 primitives and macros, ranging from 2-input AND gates to 16-bit accumulators, and includes arithmetic functions, comparators, counters, data registers, decoders, encoders, I/O functions, latches, Boolean functions, multiplexers, shift registers, and barrel shifters.

The design environment supports hierarchical design entry. These hierarchical design elements are automatically combined by the implementation tools. Different design entry tools can be combined within a hierarchical design, thus allowing the most convenient entry method to be used for each portion of the design.

Design Implementation

The place-and-route tools (PAR) automatically provide the implementation flow described in this section. The partitioner takes the EDIF netlist for the design and maps the logic into the architectural resources of the FPGA (CLBs and IOBs, for example). The placer then determines the best locations for these blocks based on their interconnections and the desired performance. Finally, the router interconnects the blocks.

The PAR algorithms support fully automatic implementation of most designs. For demanding applications, however, the user can exercise various degrees of control over the process. User partitioning, placement, and routing information is optionally specified during the design-entry process. The implementation of highly structured designs can benefit greatly from basic floorplanning.

The implementation software incorporates timing-driven placement and routing. Designers specify timing requirements along entire paths during design entry. The timing path analysis routines in PAR then recognize these user-specified requirements and accommodate them.

Timing requirements are entered in a form directly relating to the system requirements, such as the targeted clock frequency, or the maximum allowable delay between two registers. In this way, the overall performance of the system along entire signal paths is automatically tailored to user-generated specifications. Specific timing information for individual nets is unnecessary.

Design Verification

In addition to conventional software simulation, FPGA users can use in-circuit debugging techniques. Because Xilinx devices are infinitely reprogrammable, designs can be verified in real time without the need for extensive sets of software simulation vectors.

The development system supports both software simulation and in-circuit debugging techniques. For simulation, the system extracts the post-layout timing information from the design database, and back-annotates this information into the netlist for use by the simulator. Alternatively, the user can verify timing-critical portions of the design using the static timing analyzer.

For in-circuit debugging, the development system includes a download cable, which connects the FPGA in the target system to a PC or workstation. After downloading the design into the FPGA, the designer can read back the contents of the flip-flops, and so observe the internal logic state. Simple modifications can be downloaded into the system in a matter of minutes.

Signals

There are two kinds of pins that are used to configure Spartan-II devices: Dedicated pins perform only specific configuration-related functions; the other pins can serve as general purpose I/Os once user operation has begun.

The dedicated pins comprise the mode pins (M2, M1, M0), the configuration clock pin (CCLK), the $\overline{\text{PROGRAM}}$ pin, the DONE pin and the boundary-scan pins (TDI, TDO, TMS, TCK). Depending on the selected configuration mode, CCLK may be an output generated by the FPGA, or may be generated externally, and provided to the FPGA as an input.

Note that some configuration pins can act as outputs. For correct operation, these pins require a V_{CCO} of 3.3V to drive an LVTTTL signal or 2.5V to drive an LVC MOS signal. All the relevant pins fall in banks 2 or 3. The $\overline{\text{CS}}$ and $\overline{\text{WRITE}}$ pins for Slave Parallel mode are located in bank 1.

For a more detailed description than that given below, see "Pinout Tables" in Module 4 and [XAPP176](#), *Spartan-II FPGA Series Configuration and Readback*.

The Process

The sequence of steps necessary to configure Spartan-II devices are shown in [Figure 11](#). The overall flow can be divided into three different phases.

- Initiating Configuration
- Configuration memory clear
- Loading data frames
- Start-up

The memory clearing and start-up phases are the same for all configuration modes; however, the steps for the loading of data frames are different. Thus, the details for data frame loading are described separately in the sections devoted to each mode.

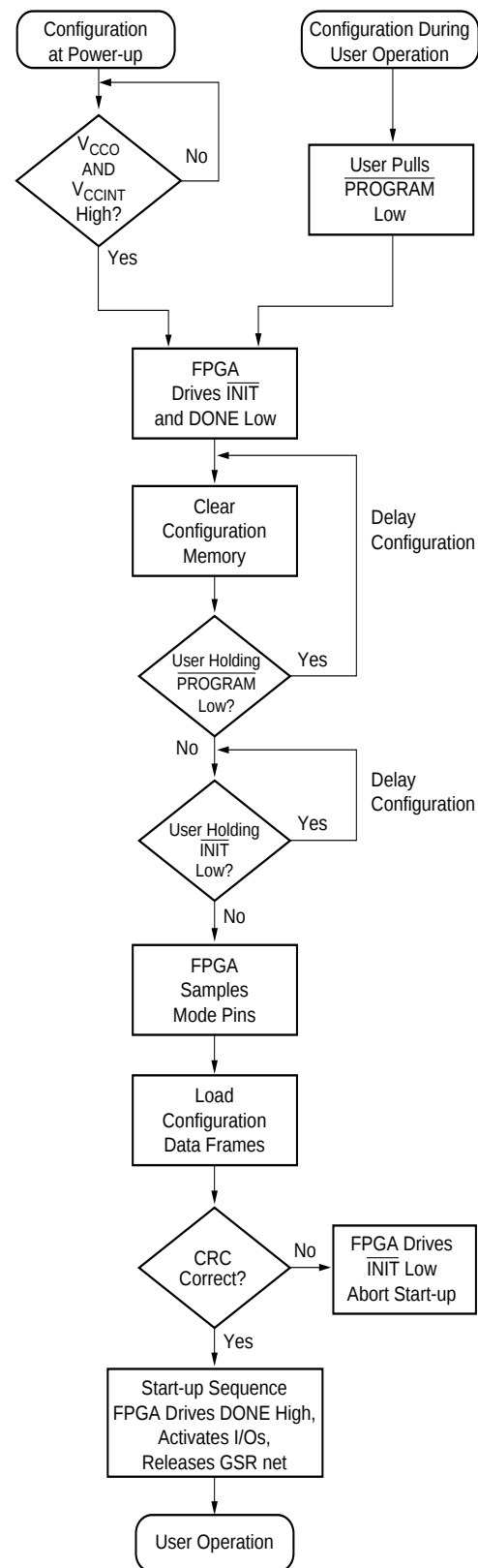
Initiating Configuration

There are two different ways to initiate the configuration process: applying power to the device or asserting the $\overline{\text{PROGRAM}}$ input.

Configuration on power-up occurs automatically unless it is delayed by the user, as described in a separate section below. The waveform for configuration on power-up is shown in [Figure 12](#), page 19. Before configuration can begin, V_{CCO} Bank 2 must be greater than 1.0V. Furthermore, all V_{CCINT} power pins must be connected to a 2.5V supply. For more information on delaying configuration, see "Clearing Configuration Memory," page 19.

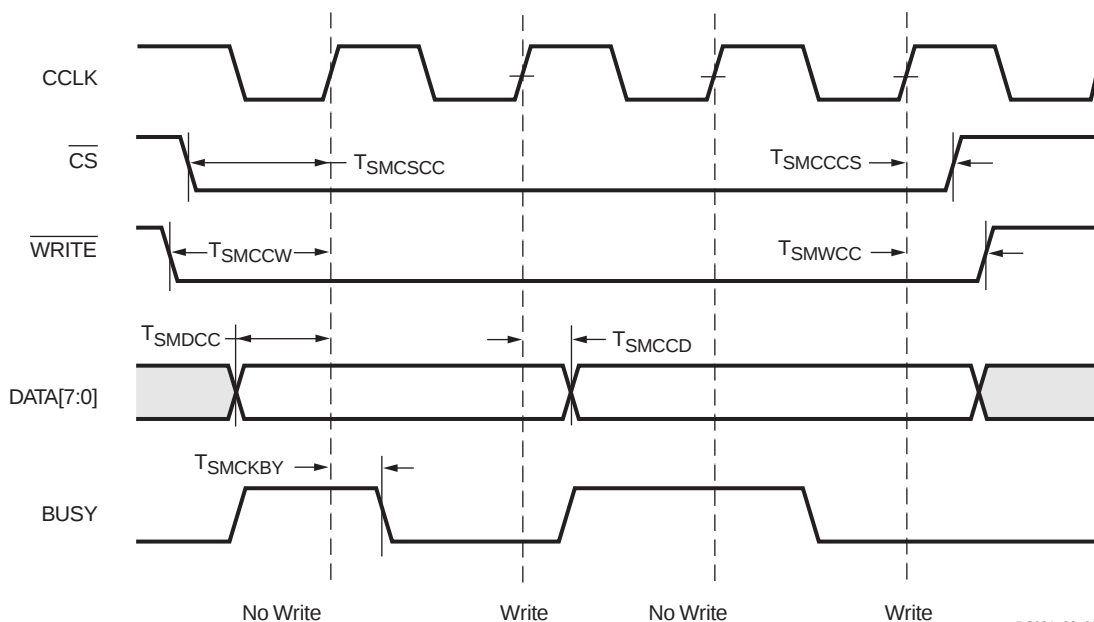
Once in user operation, the device can be re-configured simply by pulling the $\overline{\text{PROGRAM}}$ pin Low. The device acknowledges the beginning of the configuration process

by driving DONE Low, then enters the memory-clearing phase.



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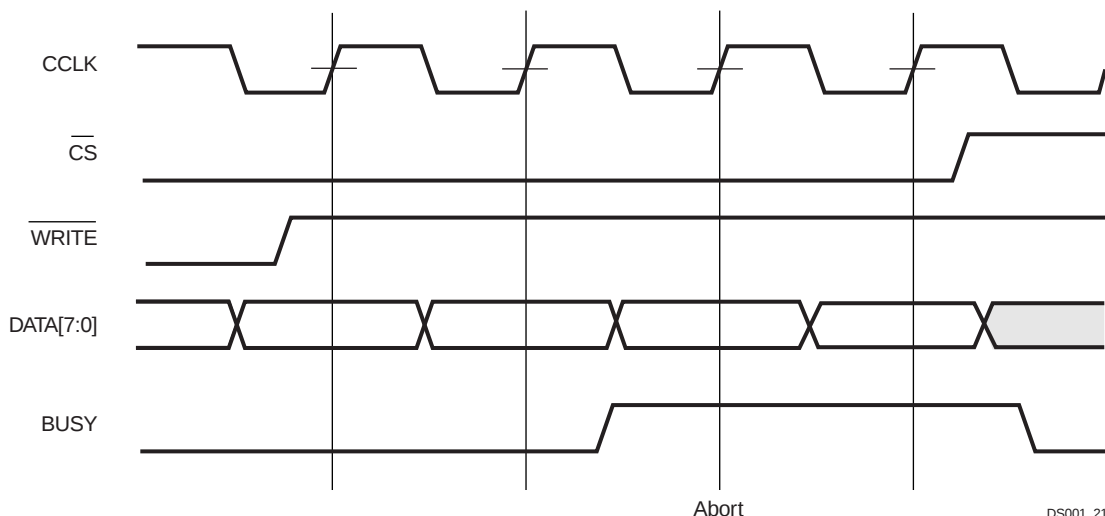
Figure 11: Configuration Flow Diagram



DS001_20_061200

Symbol		Description		Units
T_{SMDC}	CCLK	D0-D7 setup/hold	5	ns, min
T_{SMCCD}		D0-D7 hold	0	ns, min
T_{SMCSCC}		$\overline{CS}$ setup	7	ns, min
T_{SMCCCS}		$\overline{CS}$ hold	0	ns, min
T_{SMCCW}		$\overline{WRITE}$ setup	7	ns, min
T_{SMWCC}		$\overline{WRITE}$ hold	0	ns, min
T_{SMCKBY}		BUSY propagation delay	12	ns, max
F_{CC}		Maximum frequency	66	MHz, max
F_{CCNH}		Maximum frequency with no handshake	50	MHz, max

Figure 20: Slave Parallel Write Timing



DS001_21_032300

Figure 21: Slave Parallel Write Abort Waveforms

At the third rising edge of CLKA, the T_{BCCS} parameter is violated with two writes to memory location 0x0F. The DOA and DOB busses reflect the contents of the DIA and DIB busses, but the stored value at 0x7E is invalid.

At the fourth rising edge of CLKA, a read operation is performed at memory location 0x0F and invalid data is present on the DOA bus. Port B also executes a read operation to memory location 0x0F and also reads invalid data.

At the fifth rising edge of CLKA a read operation is performed that does not violate the T_{BCCS} parameter to the previous write of 0x7E by Port B. The DOA bus reflects the recently written value by Port B.

Initialization

The block RAM memory can initialize during the device configuration sequence. The 16 initialization properties of 64 hex values each (a total of 4096 bits) set the initialization of each RAM. These properties appear in [Table 14](#). Any initialization properties not explicitly set configure as zeros. Partial initialization strings pad with zeros. Initialization strings greater than 64 hex values generate an error. The RAMs can be simulated with the initialization values using generics in VHDL simulators and parameters in Verilog simulators.

Initialization in VHDL

The block RAM structures may be initialized in VHDL for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the VHDL code uses a generic to pass the initialization.

Initialization in Verilog

The block RAM structures may be initialized in Verilog for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the Verilog code uses a defparam to pass the initialization.

Block Memory Generation

The CORE Generator™ software generates memory structures using the block RAM features. This program outputs VHDL or Verilog simulation code templates and an EDIF file for inclusion in a design.

Table 14: RAM Initialization Properties

Property	Memory Cells
INIT_00	255 to 0
INIT_01	511 to 256
INIT_02	767 to 512
INIT_03	1023 to 768
INIT_04	1279 to 1024

Table 14: RAM Initialization Properties

Property	Memory Cells
INIT_05	1535 to 1280
INIT_06	1791 to 1536
INIT_07	2047 to 1792
INIT_08	2303 to 2048
INIT_09	2559 to 2304
INIT_0a	2815 to 2560
INIT_0b	3071 to 2816
INIT_0c	3327 to 3072
INIT_0d	3583 to 3328
INIT_0e	3839 to 3584
INIT_0f	4095 to 3840

For design examples and more information on using the Block RAM, see [XAPP173, Using Block SelectRAM+ Memory in Spartan-II FPGAs](#).

Using Versatile I/O

The Spartan-II FPGA family includes a highly configurable, high-performance I/O resource called Versatile I/O to provide support for a wide variety of I/O standards. The Versatile I/O resource is a robust set of features including programmable control of output drive strength, slew rate, and input delay and hold time. Taking advantage of the flexibility and Versatile I/O features and the design considerations described in this document can improve and simplify system level design.

Introduction

As FPGAs continue to grow in size and capacity, the larger and more complex systems designed for them demand an increased variety of I/O standards. Furthermore, as system clock speeds continue to increase, the need for high-performance I/O becomes more important. While chip-to-chip delays have an increasingly substantial impact on overall system speed, the task of achieving the desired system performance becomes more difficult with the proliferation of low-voltage I/O standards. Versatile I/O, the revolutionary input/output resources of Spartan-II devices, has resolved this potential problem by providing a highly configurable, high-performance alternative to the I/O resources of more conventional programmable devices. The Spartan-II FPGA Versatile I/O features combine the flexibility and time-to-market advantages of programmable logic with the high performance previously available only with ASICs and custom ICs.

Each Versatile I/O block can support up to 16 I/O standards. Supporting such a variety of I/O standards allows the

IOBUF_<slew_rate>_<drive_strength>

<slew_rate> can be either F (Fast), or S (Slow) and <drive_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).

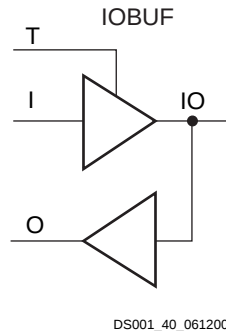


Figure 40: Input/Output Buffer Primitive (IOBUF)

When the IOBUF primitive supports an I/O standard such as LVTTTL, LVCMOS, or PCI33_5, the IBUF automatically configures as a 5V tolerant input buffer unless the V_{CCO} for the bank is less than 2V. If the single-ended IBUF is placed in a bank with an HSTL standard ($V_{CCO} < 2V$), the input buffer is not 5V tolerant.

The voltage reference signal is "banked" within the Spartan-II device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See Figure 36, page 39 for a representation of the Spartan-II FPGA I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input.

Additional restrictions on the Versatile I/O IOBUF placement require that within a given V_{CCO} bank each IOBUF must share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within the same V_{CCO} bank. The LOC property can specify a location for the IOBUF.

An optional delay element is associated with the input path in each IOBUF. When the IOBUF drives an input flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Override this default with the NODELAY=TRUE property.

In the case when the IOBUF does not drive an input flip-flop within the IOB, the delay element de-activates by default to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak "keeper" circuit. Control this feature by adding the appropriate primitive to the output net of the IOBUF (PULLUP, PULLDOWN, or KEEPER).

Versatile I/O Properties

Access to some of the Versatile I/O features (for example, location constraints, input delay, output drive strength, and slew rate) is available through properties associated with these features.

Input Delay Properties

An optional delay element is associated with each IBUF. When the IBUF drives a flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Use the NODELAY=TRUE property to override this default.

In the case when the IBUF does not drive a flip-flop within the IOB, the delay element by default de-activates to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

IOB Flip-Flop/Latch Property

The I/O Block (IOB) includes an optional register on the input path, an optional register on the output path, and an optional register on the 3-state control pin. The design implementation software automatically takes advantage of these registers when the following option for the Map program is specified:

```
map -pr b <filename>
```

Alternatively, the IOB = TRUE property can be placed on a register to force the mapper to place the register in an IOB.

Location Constraints

Specify the location of each Versatile I/O primitive with the location constraint LOC attached to the Versatile I/O primitive. The external port identifier indicates the value of the location constrain. The format of the port identifier depends on the package chosen for the specific design.

The LOC properties use the following form:

```
LOC=A42
```

```
LOC=P37
```

Output Slew Rate Property

In the case of the LVTTTL output buffers (OBUF, OBUFT, and IOBUF), slew rate control can be programmed with the SLEW= property. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals. The SLEW= property has one of the two following values.

```
SLEW=SLOW
```

```
SLEW=FAST
```

Output Drive Strength Property

For the LVTTTL output buffers (OBUF, OBUFT, and IOBUF, the desired drive strength can be specified with the DRIVE=

HSTL Class III

A sample circuit illustrating a valid termination technique for HSTL_III appears in Figure 45. DC voltage specifications appear in Table 23 for the HSTL_III standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.

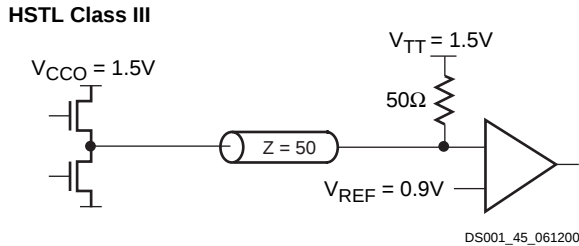


Figure 45: Terminated HSTL Class III

Table 23: HSTL Class III Voltage Specification

Parameter	Min	Typ	Max
V_{CCO}	1.40	1.50	1.60
$V_{REF}^{(1)}$	-	0.90	-
V_{TT}	-	V_{CCO}	-
V_{IH}	$V_{REF} + 0.1$	-	-
V_{IL}	-	-	$V_{REF} - 0.1$
V_{OH}	$V_{CCO} - 0.4$	-	-
V_{OL}	-	-	0.4
I_{OH} at V_{OH} (mA)	-8	-	-
I_{OL} at V_{OL} (mA)	24	-	-

Notes:

- Per EIA/JESD8-6, "The value of V_{REF} is to be selected by the user to provide optimum noise margin in the use conditions specified by the user."

HSTL Class IV

A sample circuit illustrating a valid termination technique for HSTL_IV appears in Figure 46. DC voltage specifications appear in Table 24 for the HSTL_IV standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.

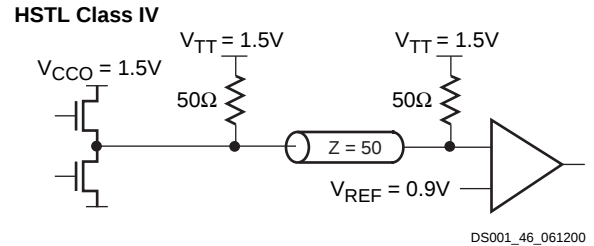


Figure 46: Terminated HSTL Class IV

Table 24: HSTL Class IV Voltage Specification

Parameter	Min	Typ	Max
V_{CCO}	1.40	1.50	1.60
V_{REF}	-	0.90	-
V_{TT}	-	V_{CCO}	-
V_{IH}	$V_{REF} + 0.1$	-	-
V_{IL}	-	-	$V_{REF} - 0.1$
V_{OH}	$V_{CCO} - 0.4$	-	-
V_{OL}	-	-	0.4
I_{OH} at V_{OH} (mA)	-8	-	-
I_{OL} at V_{OL} (mA)	48	-	-

Notes:

- Per EIA/JESD8-6, "The value of V_{REF} is to be selected by the user to provide optimum noise margin in the use conditions specified by the user."

IOB Output Delay Adjustments for Different Standards⁽¹⁾

Output delays terminating at a pad are specified for LVTTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays by the values shown. A delay adjusted in this way constitutes a worst-case limit.

Symbol	Description	Standard	Speed Grade		Units
			-6	-5	
Output Delay Adjustments (Adj)					
T _{OLVTTL_S2}	Standard-specific adjustments for output delays terminating at pads (based on standard capacitive load, C _{SL})	LVTTTL, Slow, 2 mA	14.2	16.9	ns
T _{OLVTTL_S4}		4 mA	7.2	8.6	ns
T _{OLVTTL_S6}		6 mA	4.7	5.5	ns
T _{OLVTTL_S8}		8 mA	2.9	3.5	ns
T _{OLVTTL_S12}		12 mA	1.9	2.2	ns
T _{OLVTTL_S16}		16 mA	1.7	2.0	ns
T _{OLVTTL_S24}		24 mA	1.3	1.5	ns
T _{OLVTTL_F2}		LVTTTL, Fast, 2 mA	12.6	15.0	ns
T _{OLVTTL_F4}		4 mA	5.1	6.1	ns
T _{OLVTTL_F6}		6 mA	3.0	3.6	ns
T _{OLVTTL_F8}		8 mA	1.0	1.2	ns
T _{OLVTTL_F12}		12 mA	0	0	ns
T _{OLVTTL_F16}		16 mA	−0.1	−0.1	ns
T _{OLVTTL_F24}		24 mA	−0.1	−0.2	ns
T _{OLVCMOS2}		LVC MOS2	0.2	0.2	ns
T _{OPCI33_3}		PCI, 33 MHz, 3.3V	2.4	2.9	ns
T _{OPCI33_5}		PCI, 33 MHz, 5.0V	2.9	3.5	ns
T _{OPCI66_3}		PCI, 66 MHz, 3.3V	−0.3	−0.4	ns
T _{OGTL}		GTL	0.6	0.7	ns
T _{OGTLP}		GTL+	0.9	1.1	ns
T _{OHSTL_I}		HSTL I	−0.4	−0.5	ns
T _{OHSTL_III}		HSTL III	−0.8	−1.0	ns
T _{OHSTL_IV}		HSTL IV	−0.9	−1.1	ns
T _{OSSTL2_I}		SSTL2 I	−0.4	−0.5	ns
T _{OSSTL2_II}		SSTL2 II	−0.8	−1.0	ns
T _{OSSTL3_I}		SSTL3 I	−0.4	−0.5	ns
T _{OSSTL3_II}		SSTL3 II	−0.9	−1.1	ns
T _{OCTT}		CTT	−0.5	−0.6	ns
T _{OAGP}		AGP	−0.8	−1.0	ns

Notes:

- Output timing is measured at 1.4V with 35 pF external capacitive load for LVTTTL. For other I/O standards and different loads, see the tables "Constants for Calculating TIOOP" and "Delay Measurement Methodology," page 60.

Calculation of T_{IOOP} as a Function of Capacitance

T_{IOOP} is the propagation delay from the O Input of the IOB to the pad. The values for T_{IOOP} are based on the standard capacitive load (C_{SL}) for each I/O standard as listed in the table "Constants for Calculating T_{IOOP} ", below.

For other capacitive loads, use the formulas below to calculate an adjusted propagation delay, T_{IOOP1} .

$$T_{IOOP1} = T_{IOOP} + Adj + (C_{LOAD} - C_{SL}) * F_L$$

Where:

Adj is selected from "IOB Output Delay Adjustments for Different Standards", page 59, according to the I/O standard used

C_{LOAD} is the capacitive load for the design

F_L is the capacitance scaling factor

Delay Measurement Methodology

Standard	$V_L^{(1)}$	$V_H^{(1)}$	Meas. Point	V_{REF} Typ ⁽²⁾
LVTTL	0	3	1.4	-
LVC MOS2	0	2.5	1.125	-
PCI33_5	Per PCI Spec			-
PCI33_3	Per PCI Spec			-
PCI66_3	Per PCI Spec			-
GTL	$V_{REF} - 0.2$	$V_{REF} + 0.2$	V_{REF}	0.80
GTL+	$V_{REF} - 0.2$	$V_{REF} + 0.2$	V_{REF}	1.0
HSTL Class I	$V_{REF} - 0.5$	$V_{REF} + 0.5$	V_{REF}	0.75
HSTL Class III	$V_{REF} - 0.5$	$V_{REF} + 0.5$	V_{REF}	0.90
HSTL Class IV	$V_{REF} - 0.5$	$V_{REF} + 0.5$	V_{REF}	0.90
SSTL3 I and II	$V_{REF} - 1.0$	$V_{REF} + 1.0$	V_{REF}	1.5
SSTL2 I and II	$V_{REF} - 0.75$	$V_{REF} + 0.75$	V_{REF}	1.25
CTT	$V_{REF} - 0.2$	$V_{REF} + 0.2$	V_{REF}	1.5
AGP	$V_{REF} - (0.2 \times V_{CCO})$	$V_{REF} + (0.2 \times V_{CCO})$	V_{REF}	Per AGP Spec

Notes:

- Input waveform switches between V_L and V_H .
- Measurements are made at V_{REF} Typ, Maximum, and Minimum. Worst-case values are reported.
- I/O parameter measurements are made with the capacitance values shown in the table, "Constants for Calculating T_{IOOP} ". See Xilinx application note [XAPP179](#) for the appropriate terminations.
- I/O standard measurements are reflected in the IBIS model information except where the IBIS format precludes it.

Constants for Calculating T_{IOOP}

Standard	$C_{SL}^{(1)}$ (pF)	F_L (ns/pF)
LVTTL Fast Slew Rate, 2 mA drive	35	0.41
LVTTL Fast Slew Rate, 4 mA drive	35	0.20
LVTTL Fast Slew Rate, 6 mA drive	35	0.13
LVTTL Fast Slew Rate, 8 mA drive	35	0.079
LVTTL Fast Slew Rate, 12 mA drive	35	0.044
LVTTL Fast Slew Rate, 16 mA drive	35	0.043
LVTTL Fast Slew Rate, 24 mA drive	35	0.033
LVTTL Slow Slew Rate, 2 mA drive	35	0.41
LVTTL Slow Slew Rate, 4 mA drive	35	0.20
LVTTL Slow Slew Rate, 6 mA drive	35	0.100
LVTTL Slow Slew Rate, 8 mA drive	35	0.086
LVTTL Slow Slew Rate, 12 mA drive	35	0.058
LVTTL Slow Slew Rate, 16 mA drive	35	0.050
LVTTL Slow Slew Rate, 24 mA drive	35	0.048
LVC MOS2	35	0.041
PCI 33 MHz 5V	50	0.050
PCI 33 MHz 3.3V	10	0.050
PCI 66 MHz 3.3V	10	0.033
GTL	0	0.014
GTL+	0	0.017
HSTL Class I	20	0.022
HSTL Class III	20	0.016
HSTL Class IV	20	0.014
SSTL2 Class I	30	0.028
SSTL2 Class II	30	0.016
SSTL3 Class I	30	0.029
SSTL3 Class II	30	0.016
CTT	20	0.035
AGP	10	0.037

Notes:

- I/O parameter measurements are made with the capacitance values shown above. See Xilinx application note [XAPP179](#) for the appropriate terminations.
- I/O standard measurements are reflected in the IBIS model information except where the IBIS format precludes it.

CLB Switching Characteristics

Delays originating at F/G inputs vary slightly according to the input used. The values listed below are worst-case. Precise values are provided by the timing analyzer.

Symbol	Description	Speed Grade				Units
		-6		-5		
		Min	Max	Min	Max	
Combinatorial Delays						
T _{ILO}	4-input function: F/G inputs to X/Y outputs	-	0.6	-	0.7	ns
T _{IF5}	5-input function: F/G inputs to F5 output	-	0.7	-	0.9	ns
T _{IF5X}	5-input function: F/G inputs to X output	-	0.9	-	1.1	ns
T _{IF6Y}	6-input function: F/G inputs to Y output via F6 MUX	-	1.0	-	1.1	ns
T _{F5INY}	6-input function: F5IN input to Y output	-	0.4	-	0.4	ns
T _{IFNCTL}	Incremental delay routing through transparent latch to XQ/YQ outputs	-	0.7	-	0.9	ns
T _{BYYB}	BY input to YB output	-	0.6	-	0.7	ns
Sequential Delays						
T _{CKO}	FF clock CLK to XQ/YQ outputs	-	1.1	-	1.3	ns
T _{CKLO}	Latch clock CLK to XQ/YQ outputs	-	1.2	-	1.5	ns
Setup/Hold Times with Respect to Clock CLK ⁽¹⁾						
T _{ICK} / T _{CKI}	4-input function: F/G inputs	1.3 / 0	-	1.4 / 0	-	ns
T _{IF5CK} / T _{CKIF5}	5-input function: F/G inputs	1.6 / 0	-	1.8 / 0	-	ns
T _{F5INCK} / T _{CKF5IN}	6-input function: F5IN input	1.0 / 0	-	1.1 / 0	-	ns
T _{IF6CK} / T _{CKIF6}	6-input function: F/G inputs via F6 MUX	1.6 / 0	-	1.8 / 0	-	ns
T _{DICK} / T _{CKDI}	BX/BY inputs	0.8 / 0	-	0.8 / 0	-	ns
T _{CECK} / T _{CKCE}	CE input	0.9 / 0	-	0.9 / 0	-	ns
T _{RCK} / T _{CKR}	SR/BY inputs (synchronous)	0.8 / 0	-	0.8 / 0	-	ns
Clock CLK						
T _{CH}	Minimum pulse width, High	-	1.9	-	1.9	ns
T _{CL}	Minimum pulse width, Low	-	1.9	-	1.9	ns
Set/Reset						
T _{RPW}	Minimum pulse width, SR/BY inputs	3.1	-	3.1	-	ns
T _{RQ}	Delay from SR/BY inputs to XQ/YQ outputs (asynchronous)	-	1.1	-	1.3	ns
T _{IOGSRQ}	Delay from GSR to XQ/YQ outputs	-	9.9	-	11.7	ns
F _{TOG}	Toggle frequency (for export control)	-	263	-	263	MHz

Notes:

1. A zero hold time listing indicates no hold time or a negative hold time.

Package Thermal Characteristics

Table 39 provides the thermal characteristics for the various Spartan-II FPGA package offerings. This information is also available using the Thermal Query tool on xilinx.com (www.xilinx.com/cgi-bin/thermal/thermal.pl).

The junction-to-case thermal resistance (θ_{JC}) indicates the difference between the temperature measured on the package body (case) and the die junction temperature per watt of power consumption. The junction-to-board (θ_{JB})

value similarly reports the difference between the board and junction temperature. The junction-to-ambient (θ_{JA}) value reports the temperature difference between the ambient environment and the junction temperature. The θ_{JA} value is reported at different air velocities, measured in linear feet per minute (LFM). The “Still Air (0 LFM)” column shows the θ_{JA} value in a system without a fan. The thermal resistance drops with increasing air flow.

Table 39: Spartan-II Package Thermal Characteristics

Package	Device	Junction-to-Case (θ_{JC})	Junction-to-Board (θ_{JB})	Junction-to-Ambient (θ_{JA}) at Different Air Flows				Units
				Still Air (0 LFM)	250 LFM	500 LFM	750 LFM	
VQ100 VQG100	XC2S15	11.3	N/A	44.1	36.7	34.2	33.3	°C/Watt
	XC2S30	10.1	N/A	40.7	33.9	31.5	30.8	°C/Watt
TQ144 TQG144	XC2S15	7.3	N/A	38.6	30.0	25.7	24.1	°C/Watt
	XC2S30	6.7	N/A	34.7	27.0	23.1	21.7	°C/Watt
	XC2S50	5.8	N/A	32.2	25.1	21.4	20.1	°C/Watt
	XC2S100	5.3	N/A	31.4	24.4	20.9	19.6	°C/Watt
CS144 CSG144	XC2S30	2.8	N/A	34.0	26.0	23.9	23.2	°C/Watt
PQ208 PQG208	XC2S50	6.7	N/A	25.2	18.6	16.4	15.2	°C/Watt
	XC2S100	5.9	N/A	24.6	18.1	16.0	14.9	°C/Watt
	XC2S150	5.0	N/A	23.8	17.6	15.6	14.4	°C/Watt
	XC2S200	4.1	N/A	23.0	17.0	15.0	13.9	°C/Watt
FG256 FGG256	XC2S50	7.1	17.6	27.2	21.4	20.3	19.8	°C/Watt
	XC2S100	5.8	15.1	25.1	19.5	18.3	17.8	°C/Watt
	XC2S150	4.6	12.7	23.0	17.6	16.3	15.8	°C/Watt
	XC2S200	3.5	10.7	21.4	16.1	14.7	14.2	°C/Watt
FG456 FGG456	XC2S150	2.0	N/A	21.9	17.3	15.8	15.2	°C/Watt
	XC2S200	2.0	N/A	21.0	16.6	15.1	14.5	°C/Watt

XC2S50 Device Pinouts

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
GND	-	P143	P1	GND*	-
TMS	-	P142	P2	D3	-
I/O	7	P141	P3	C2	149
I/O	7	-	-	A2	152
I/O	7	P140	P4	B1	155
I/O	7	-	-	E3	158
I/O	7	-	P5	D2	161
GND	-	-	-	GND*	-
I/O, V _{REF}	7	P139	P6	C1	164
I/O	7	-	P7	F3	167
I/O	7	-	-	E2	170
I/O	7	P138	P8	E4	173
I/O	7	P137	P9	D1	176
I/O	7	P136	P10	E1	179
GND	-	P135	P11	GND*	-
V _{CCO}	7	-	P12	V _{CCO} Bank 7*	-
V _{CCINT}	-	-	P13	V _{CCINT} *	-
I/O	7	P134	P14	F2	182
I/O	7	P133	P15	G3	185
I/O	7	-	-	F1	188
I/O	7	-	P16	F4	191
I/O	7	-	P17	F5	194
I/O	7	-	P18	G2	197
GND	-	-	P19	GND*	-
I/O, V _{REF}	7	P132	P20	H3	200
I/O	7	P131	P21	G4	203
I/O	7	-	-	H2	206
I/O	7	P130	P22	G5	209
I/O	7	-	P23	H4	212
I/O, IRDY ⁽¹⁾	7	P129	P24	G1	215
GND	-	P128	P25	GND*	-
V _{CCO}	7	P127	P26	V _{CCO} Bank 7*	-
V _{CCO}	6	P127	P26	V _{CCO} Bank 6*	-
I/O, TRDY ⁽¹⁾	6	P126	P27	J2	218
V _{CCINT}	-	P125	P28	V _{CCINT} *	-
I/O	6	P124	P29	H1	224
I/O	6	-	-	J4	227
I/O	6	P123	P30	J1	230
I/O, V _{REF}	6	P122	P31	J3	233

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
GND	-	-	P32	GND*	-
I/O	6	-	P33	K5	236
I/O	6	-	P34	K2	239
I/O	6	-	P35	K1	242
I/O	6	-	-	K3	245
I/O	6	P121	P36	L1	248
I/O	6	P120	P37	L2	251
V _{CCINT}	-	-	P38	V _{CCINT} *	-
V _{CCO}	6	-	P39	V _{CCO} Bank 6*	-
GND	-	P119	P40	GND*	-
I/O	6	P118	P41	K4	254
I/O	6	P117	P42	M1	257
I/O	6	P116	P43	L4	260
I/O	6	-	-	M2	263
I/O	6	-	P44	L3	266
I/O, V _{REF}	6	P115	P45	N1	269
GND	-	-	-	GND*	-
I/O	6	-	P46	P1	272
I/O	6	-	-	L5	275
I/O	6	P114	P47	N2	278
I/O	6	-	-	M4	281
I/O	6	P113	P48	R1	284
I/O	6	P112	P49	M3	287
M1	-	P111	P50	P2	290
GND	-	P110	P51	GND*	-
M0	-	P109	P52	N3	291
V _{CCO}	6	P108	P53	V _{CCO} Bank 6*	-
V _{CCO}	5	P107	P53	V _{CCO} Bank 5*	-
M2	-	P106	P54	R3	292
I/O	5	-	-	N5	299
I/O	5	P103	P57	T2	302
I/O	5	-	-	P5	305
I/O	5	-	P58	T3	308
GND	-	-	-	GND*	-
I/O, V _{REF}	5	P102	P59	T4	311
I/O	5	-	P60	M6	314
I/O	5	-	-	T5	317
I/O	5	P101	P61	N6	320
I/O	5	P100	P62	R5	323

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
I/O	3	-	-	J14	503
I/O	3	P56	P127	K15	506
V _{CCINT}	-	P55	P128	V _{CCINT} *	-
I/O, TRDY ⁽¹⁾	3	P54	P129	J15	512
V _{CCO}	3	P53	P130	V _{CCO} Bank 3*	-
V _{CCO}	2	P53	P130	V _{CCO} Bank 2*	-
GND	-	P52	P131	GND*	-
I/O, IRDY ⁽¹⁾	2	P51	P132	H16	515
I/O	2	-	P133	H14	518
I/O	2	P50	P134	H15	521
I/O	2	-	-	J13	524
I/O (D3)	2	P49	P135	G16	527
I/O, V _{REF}	2	P48	P136	H13	530
GND	-	-	P137	GND*	-
I/O	2	-	P138	G14	533
I/O	2	-	P139	G15	536
I/O	2	-	P140	G12	539
I/O	2	-	-	F16	542
I/O	2	P47	P141	G13	545
I/O (D2)	2	P46	P142	F15	548
V _{CCINT}	-	-	P143	V _{CCINT} *	-
V _{CCO}	2	-	P144	V _{CCO} Bank 2*	-
GND	-	P45	P145	GND*	-
I/O (D1)	2	P44	P146	E16	551
I/O	2	P43	P147	F14	554
I/O	2	P42	P148	D16	557
I/O	2	-	-	F12	560
I/O	2	-	P149	E15	563
I/O, V _{REF}	2	P41	P150	F13	566
GND	-	-	-	GND*	-
I/O	2	-	P151	E14	569
I/O	2	-	-	C16	572
I/O	2	P40	P152	E13	575
I/O	2	-	-	B16	578
I/O (DIN, D0)	2	P39	P153	D14	581
I/O (DOUT, BUSY)	2	P38	P154	C15	584
CCLK	2	P37	P155	D15	587
V _{CCO}	2	P36	P156	V _{CCO} Bank 2*	-

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
V _{CCO}	1	P35	P156	V _{CCO} Bank 1*	-
TDO	2	P34	P157	B14	-
GND	-	P33	P158	GND*	-
TDI	-	P32	P159	A15	-
I/O ($\overline{\text{CS}}$)	1	P31	P160	B13	0
I/O ($\overline{\text{WRITE}}$)	1	P30	P161	C13	3
I/O	1	-	-	C12	6
I/O	1	P29	P162	A14	9
I/O	1	-	-	D12	12
I/O	1	-	P163	B12	15
GND	-	-	-	GND*	-
I/O, V _{REF}	1	P28	P164	C11	18
I/O	1	-	P165	A13	21
I/O	1	-	-	D11	24
I/O	1	-	P166	A12	27
I/O	1	P27	P167	E11	30
I/O	1	P26	P168	B11	33
GND	-	P25	P169	GND*	-
V _{CCO}	1	-	P170	V _{CCO} Bank 1*	-
V _{CCINT}	-	P24	P171	V _{CCINT} *	-
I/O	1	P23	P172	A11	36
I/O	1	P22	P173	C10	39
I/O	1	-	P174	B10	45
I/O	1	-	P175	D10	48
I/O	1	-	P176	A10	51
GND	-	-	P177	GND*	-
I/O, V _{REF}	1	P21	P178	B9	54
I/O	1	-	P179	E10	57
I/O	1	-	-	A9	60
I/O	1	P20	P180	D9	63
I/O	1	P19	P181	A8	66
I, GCK2	1	P18	P182	C9	72
GND	-	P17	P183	GND*	-
V _{CCO}	1	P16	P184	V _{CCO} Bank 1*	-
V _{CCO}	0	P16	P184	V _{CCO} Bank 0*	-
I, GCK3	0	P15	P185	B8	73
V _{CCINT}	-	P14	P186	V _{CCINT} *	-
I/O	0	P13	P187	A7	80

XC2S100 Device Pinouts (Continued)

XC2S100 Pad Name		TQ144	PQ208	FG256	FG456	Bndry Scan
Function	Bank					
I/O, V _{REF}	4	P79	P95	T11	AB16	502
I/O	4	-	-	-	AB17	505
I/O	4	P78	P96	N11	V15	508
I/O	4	-	-	R12	Y16	511
I/O	4	-	P97	P11	AB18	517
I/O, V _{REF}	4	P77	P98	T12	AB19	520
V _{CCO}	4	-	-	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	-	-	GND*	GND*	-
I/O	4	-	P99	T13	Y17	523
I/O	4	-	-	N12	V16	526
I/O	4	-	-	-	W17	529
I/O	4	P76	P100	R13	AB20	532
I/O	4	-	-	P12	AA19	535
I/O	4	P75	P101	P13	AA20	541
I/O	4	P74	P102	T14	W18	544
GND	-	P73	P103	GND*	GND*	-
DONE	3	P72	P104	R14	Y19	547
V _{CCO}	4	P71	P105	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
V _{CCO}	3	P70	P105	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
PROGRAM	-	P69	P106	P15	W20	550
I/O (INIT)	3	P68	P107	N15	V19	551
I/O (D7)	3	P67	P108	N14	Y21	554
I/O	3	-	-	T15	W21	560
I/O	3	P66	P109	M13	U20	563
I/O	3	-	-	-	U19	566
I/O	3	-	-	R16	T18	569
I/O	3	-	P110	M14	W22	572
GND	-	-	-	GND*	GND*	-
V _{CCO}	3	-	-	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
I/O, V _{REF}	3	P65	P111	L14	U21	575
I/O	3	-	P112	M15	T20	578
I/O	3	-	-	L12	T21	584
I/O	3	P64	P113	P16	R18	587
I/O	3	-	-	-	U22	590
I/O, V _{REF}	3	P63	P114	L13	R19	593
I/O (D6)	3	P62	P115	N16	T22	596
GND	-	P61	P116	GND*	GND*	-

XC2S100 Device Pinouts (Continued)

XC2S100 Pad Name		TQ144	PQ208	FG256	FG456	Bndry Scan
Function	Bank					
V _{CCO}	3	-	P117	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCINT}	-	-	P118	V _{CCINT} *	V _{CCINT} *	-
I/O (D5)	3	P60	P119	M16	R21	599
I/O	3	P59	P120	K14	P18	602
I/O	3	-	-	L16	P20	605
I/O	3	-	P121	K13	P21	608
I/O	3	-	P122	L15	N18	614
I/O	3	-	P123	K12	N20	617
GND	-	-	P124	GND*	GND*	-
I/O, V _{REF}	3	P58	P125	K16	N21	620
I/O (D4)	3	P57	P126	J16	N22	623
I/O	3	-	-	J14	M19	626
I/O	3	P56	P127	K15	M20	629
V _{CCINT}	-	P55	P128	E5	V _{CCINT} *	-
I/O, TRDY ⁽¹⁾	3	P54	P129	J15	M22	638
V _{CCO}	3	P53	P130	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCO}	2	P53	P130	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P52	P131	GND*	GND*	-
I/O, IRDY ⁽¹⁾	2	P51	P132	H16	L20	641
I/O	2	-	P133	H14	L17	644
I/O	2	P50	P134	H15	L21	650
I/O	2	-	-	J13	L22	653
I/O (D3)	2	P49	P135	G16	K20	656
I/O, V _{REF}	2	P48	P136	H13	K21	659
GND	-	-	P137	GND*	GND*	-
I/O	2	-	P138	G14	K22	662
I/O	2	-	P139	G15	J21	665
I/O	2	-	P140	G12	J18	671
I/O	2	-	-	F16	J22	674
I/O	2	P47	P141	G13	H19	677
I/O (D2)	2	P46	P142	F15	H20	680
V _{CCINT}	-	-	P143	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	2	-	P144	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P45	P145	GND*	GND*	-
I/O (D1)	2	P44	P146	E16	H22	683
I/O, V _{REF}	2	P43	P147	F14	H18	686
I/O	2	-	-	-	G21	689
I/O	2	P42	P148	D16	G18	692

XC2S100 Device Pinouts (Continued)

XC2S100 Pad Name						
Function	Bank	TQ144	PQ208	FG256	FG456	Bndry Scan
I/O	0	-	P188	A6	C10	107
I/O, V _{REF}	0	P12	P189	B7	A9	110
GND	-	-	P190	GND*	GND*	-
I/O	0	-	P191	C8	B9	113
I/O	0	-	P192	D7	E10	116
I/O	0	-	P193	E7	A8	122
I/O	0	-	-	-	D9	125
I/O	0	P11	P194	C7	E9	128
I/O	0	P10	P195	B6	A7	131
V _{CCINT}	-	P9	P196	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	0	-	P197	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
GND	-	P8	P198	GND*	GND*	-
I/O	0	P7	P199	A5	B7	134
I/O, V _{REF}	0	P6	P200	C6	E8	137
I/O	0	-	-	-	D8	140
I/O	0	-	P201	B5	C7	143
I/O	0	-	-	D6	D7	146
I/O	0	-	P202	A4	D6	152
I/O, V _{REF}	0	P5	P203	B4	C6	155
V _{CCO}	0	-	-	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
GND	-	-	-	GND*	GND*	-
I/O	0	-	P204	E6	B5	158
I/O	0	-	-	D5	E7	161
I/O	0	-	-	-	E6	164
I/O	0	P4	P205	A3	B4	167
I/O	0	-	-	C5	A3	170
I/O	0	P3	P206	B3	C5	176
TCK	-	P2	P207	C4	C4	-
V _{CCO}	0	P1	P208	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
V _{CCO}	7	P144	P208	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-

04/18/01

Notes:

1. IRDY and TRDY can only be accessed when using Xilinx PCI cores.
2. Pads labelled GND*, V_{CCINT}*, V_{CCO} Bank 0*, V_{CCO} Bank 1*, V_{CCO} Bank 2*, V_{CCO} Bank 3*, V_{CCO} Bank 4*, V_{CCO} Bank 5*, V_{CCO} Bank 6*, V_{CCO} Bank 7* are internally bonded to independent ground or power planes within the package.
3. See "VCCO Banks" for details on V_{CCO} banking.

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I/O	4	P90	R11	AA15	595
V _{CCINT}	-	P91	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	4	P92	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	P93	GND*	GND*	-
I/O	4	P94	M11	Y15	598
I/O, V _{REF}	4	P95	T11	AB16	601
I/O	4	-	-	AB17	604
I/O	4	P96	N11	V15	607
I/O	4	-	R12	Y16	610
I/O	4	-	-	AA17	613
I/O	4	-	-	W16	616
I/O	4	P97	P11	AB18	619
I/O, V _{REF}	4	P98	T12	AB19	622
V _{CCO}	4	-	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	-	GND*	GND*	-
I/O	4	P99	T13	Y17	625
I/O	4	-	N12	V16	628
I/O	4	-	-	AA18	631
I/O	4	-	-	W17	634
I/O	4	P100	R13	AB20	637
GND	-	-	GND*	GND*	-
I/O	4	-	P12	AA19	640
I/O	4	-	-	V17	643
I/O	4	-	-	Y18	646
I/O	4	P101	P13	AA20	649
I/O	4	P102	T14	W18	652
GND	-	P103	GND*	GND*	-
DONE	3	P104	R14	Y19	655
V _{CCO}	4	P105	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
V _{CCO}	3	P105	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
PROGRAM	-	P106	P15	W20	658
I/O (INIT)	3	P107	N15	V19	659
I/O (D7)	3	P108	N14	Y21	662
I/O	3	-	-	V20	665
I/O	3	-	-	AA22	668
I/O	3	-	T15	W21	671
GND	-	-	GND*	GND*	-
I/O	3	P109	M13	U20	674

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I/O	3	-	-	U19	677
I/O	3	-	-	V21	680
I/O	3	-	R16	T18	683
I/O	3	P110	M14	W22	686
GND	-	-	GND*	GND*	-
V _{CCO}	3	-	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
I/O, V _{REF}	3	P111	L14	U21	689
I/O	3	P112	M15	T20	692
I/O	3	-	-	T19	695
I/O	3	-	-	V22	698
I/O	3	-	L12	T21	701
I/O	3	P113	P16	R18	704
I/O	3	-	-	U22	707
I/O, V _{REF}	3	P114	L13	R19	710
I/O (D6)	3	P115	N16	T22	713
GND	-	P116	GND*	GND*	-
V _{CCO}	3	P117	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCINT}	-	P118	V _{CCINT} *	V _{CCINT} *	-
I/O (D5)	3	P119	M16	R21	716
I/O	3	P120	K14	P18	719
I/O	3	-	-	P19	725
I/O	3	-	L16	P20	728
I/O	3	P121	K13	P21	731
I/O	3	-	-	N19	734
I/O	3	P122	L15	N18	740
I/O	3	P123	K12	N20	743
GND	-	P124	GND*	GND*	-
V _{CCO}	3	-	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
I/O, V _{REF}	3	P125	K16	N21	746
I/O (D4)	3	P126	J16	N22	749
I/O	3	-	J14	M19	752
I/O	3	P127	K15	M20	755
I/O	3	-	-	M18	758
V _{CCINT}	-	P128	V _{CCINT} *	V _{CCINT} *	-
I/O, TRDY ⁽¹⁾	3	P129	J15	M22	764
V _{CCO}	3	P130	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCO}	2	P130	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P131	GND*	GND*	-

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I/O, IRDY ⁽¹⁾	2	P132	H16	L20	767
I/O	2	P133	H14	L17	770
I/O	2	-	-	L18	773
I/O	2	P134	H15	L21	776
I/O	2	-	J13	L22	779
I/O (D3)	2	P135	G16	K20	782
I/O, V _{REF}	2	P136	H13	K21	785
V _{CCO}	2	-	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P137	GND*	GND*	-
I/O	2	P138	G14	K22	788
I/O	2	P139	G15	J21	791
I/O	2	-	-	J20	797
I/O	2	P140	G12	J18	800
I/O	2	-	F16	J22	803
I/O	2	-	-	J19	806
I/O	2	P141	G13	H19	812
I/O (D2)	2	P142	F15	H20	815
V _{CCINT}	-	P143	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	2	P144	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P145	GND*	GND*	-
I/O (D1)	2	P146	E16	H22	818
I/O, V _{REF}	2	P147	F14	H18	821
I/O	2	-	-	G21	824
I/O	2	P148	D16	G18	827
I/O	2	-	F12	G20	830
I/O	2	-	-	G19	833
I/O	2	-	-	F22	836
I/O	2	P149	E15	F19	839
I/O, V _{REF}	2	P150	F13	F21	842
V _{CCO}	2	-	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	-	GND*	GND*	-
I/O	2	P151	E14	F20	845
I/O	2	-	C16	F18	848
I/O	2	-	-	E22	851
I/O	2	-	-	E21	854
I/O	2	P152	E13	D22	857
GND	-	-	GND*	GND*	-
I/O	2	-	B16	E20	860
I/O	2	-	-	D21	863

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I/O	2	-	-	C22	866
I/O (DIN, D0)	2	P153	D14	D20	869
I/O (DOUT, BUSY)	2	P154	C15	C21	872
CCLK	2	P155	D15	B22	875
V _{CCO}	2	P156	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
V _{CCO}	1	P156	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
TDO	2	P157	B14	A21	-
GND	-	P158	GND*	GND*	-
TDI	-	P159	A15	B20	-
I/O ($\overline{\text{CS}}$)	1	P160	B13	C19	0
I/O ($\overline{\text{WRITE}}$)	1	P161	C13	A20	3
I/O	1	-	-	B19	6
I/O	1	-	-	C18	9
I/O	1	-	C12	D17	12
GND	-	-	GND*	GND*	-
I/O	1	P162	A14	A19	15
I/O	1	-	-	B18	18
I/O	1	-	-	E16	21
I/O	1	-	D12	C17	24
I/O	1	P163	B12	D16	27
GND	-	-	GND*	GND*	-
V _{CCO}	1	-	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
I/O, V _{REF}	1	P164	C11	A18	30
I/O	1	P165	A13	B17	33
I/O	1	-	-	E15	36
I/O	1	-	-	A17	39
I/O	1	-	D11	D15	42
I/O	1	P166	A12	C16	45
I/O	1	-	-	D14	48
I/O, V _{REF}	1	P167	E11	E14	51
I/O	1	P168	B11	A16	54
GND	-	P169	GND*	GND*	-
V _{CCO}	1	P170	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
V _{CCINT}	-	P171	V _{CCINT} *	V _{CCINT} *	-
I/O	1	P172	A11	C15	57
I/O	1	P173	C10	B15	60
I/O	1	-	-	A15	66
I/O	1	-	-	F12	69

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I, GCK0	4	P80	N8	W12	636
I/O	4	P81	N9	U12	640
I/O	4	-	-	V12	646
I/O	4	P82	R9	Y12	649
I/O	4	-	N10	AA12	652
I/O	4	-	-	W13	655
I/O	4	P83	T9	AB13	661
I/O, V _{REF}	4	P84	P9	AA13	664
V _{CCO}	4	-	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	P85	GND*	GND*	-
I/O	4	P86	M10	Y13	667
I/O	4	P87	R10	V13	670
I/O	4	-	-	AB14	673
I/O	4	-	-	W14	676
I/O	4	P88	P10	AA14	679
GND	-	-	GND*	GND*	-
I/O	4	-	-	V14	682
I/O	4	-	-	Y14	685
I/O	4	-	-	W15	688
I/O	4	P89	T10	AB15	691
I/O	4	P90	R11	AA15	694
V _{CCINT}	-	P91	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	4	P92	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	P93	GND*	GND*	-
I/O	4	P94	M11	Y15	697
I/O, V _{REF}	4	P95	T11	AB16	700
I/O	4	-	-	AB17	706
I/O	4	P96	N11	V15	709
GND	-	-	GND*	GND*	-
I/O	4	-	R12	Y16	712
I/O	4	-	-	AA17	715
I/O	4	-	-	W16	718
I/O	4	P97	P11	AB18	721
I/O, V _{REF}	4	P98	T12	AB19	724
V _{CCO}	4	-	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	-	GND*	GND*	-
I/O	4	P99	T13	Y17	727
I/O	4	-	N12	V16	730
I/O	4	-	-	AA18	733

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I/O	4	-	-	W17	739
I/O, V _{REF}	4	P100	R13	AB20	742
GND	-	-	GND*	GND*	-
I/O	4	-	P12	AA19	745
I/O	4	-	-	V17	748
I/O	4	-	-	Y18	751
I/O	4	P101	P13	AA20	757
I/O	4	P102	T14	W18	760
GND	-	P103	GND*	GND*	-
DONE	3	P104	R14	Y19	763
V _{CCO}	4	P105	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
V _{CCO}	3	P105	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
PROGRAM	-	P106	P15	W20	766
I/O (INIT)	3	P107	N15	V19	767
I/O (D7)	3	P108	N14	Y21	770
I/O	3	-	-	V20	776
I/O	3	-	-	AA22	779
I/O	3	-	T15	W21	782
GND	-	-	GND*	GND*	-
I/O, V _{REF}	3	P109	M13	U20	785
I/O	3	-	-	U19	788
I/O	3	-	-	V21	794
GND	-	-	GND*	GND*	-
I/O	3	-	R16	T18	797
I/O	3	P110	M14	W22	800
GND	-	-	GND*	GND*	-
V _{CCO}	3	-	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
I/O, V _{REF}	3	P111	L14	U21	803
I/O	3	P112	M15	T20	806
I/O	3	-	-	T19	809
I/O	3	-	-	V22	812
I/O	3	-	L12	T21	815
GND	-	-	GND*	GND*	-
I/O	3	P113	P16	R18	818
I/O	3	-	-	U22	821
I/O, V _{REF}	3	P114	L13	R19	827
I/O (D6)	3	P115	N16	T22	830
GND	-	P116	GND*	GND*	-

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
V _{CCO}	1	P156	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
TDO	2	P157	B14	A21	-
GND	-	P158	GND*	GND*	-
TDI	-	P159	A15	B20	-
I/O ($\overline{\text{CS}}$)	1	P160	B13	C19	0
I/O ($\overline{\text{WRITE}}$)	1	P161	C13	A20	3
I/O	1	-	-	B19	9
I/O	1	-	-	C18	12
I/O	1	-	C12	D17	15
GND	-	-	GND*	GND*	-
I/O, V _{REF}	1	P162	A14	A19	18
I/O	1	-	-	B18	21
I/O	1	-	-	E16	27
I/O	1	-	D12	C17	30
I/O	1	P163	B12	D16	33
GND	-	-	GND*	GND*	-
V _{CCO}	1	-	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
I/O, V _{REF}	1	P164	C11	A18	36
I/O	1	P165	A13	B17	39
I/O	1	-	-	E15	42
I/O	1	-	-	A17	45
I/O	1	-	D11	D15	48
GND	-	-	GND*	GND*	-
I/O	1	P166	A12	C16	51
I/O	1	-	-	D14	54
I/O, V _{REF}	1	P167	E11	E14	60
I/O	1	P168	B11	A16	63
GND	-	P169	GND*	GND*	-
V _{CCO}	1	P170	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
V _{CCINT}	-	P171	V _{CCINT} *	V _{CCINT} *	-
I/O	1	P172	A11	C15	66
I/O	1	P173	C10	B15	69
I/O	1	-	-	E13	72
I/O	1	-	-	A15	75
I/O	1	-	-	F12	78
GND	-	-	GND*	GND*	-
I/O	1	P174	B10	C14	81
I/O	1	-	-	B14	84
I/O	1	-	-	A14	87

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I/O	1	P175	D10	D13	90
I/O	1	P176	A10	C13	93
GND	-	P177	GND*	GND*	-
V _{CCO}	1	-	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
I/O, V _{REF}	1	P178	B9	B13	96
I/O	1	P179	E10	E12	99
I/O	1	-	-	A13	105
I/O	1	-	A9	B12	108
I/O	1	P180	D9	D12	111
I/O	1	-	-	C12	114
I/O	1	P181	A8	D11	120
I, GCK2	1	P182	C9	A11	126
GND	-	P183	GND*	GND*	-
V _{CCO}	1	P184	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
V _{CCO}	0	P184	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
I, GCK3	0	P185	B8	C11	127
V _{CCINT}	-	P186	V _{CCINT} *	V _{CCINT} *	-
I/O	0	-	-	E11	137
I/O	0	P187	A7	A10	140
I/O	0	-	D8	B10	143
I/O	0	-	-	F11	146
I/O	0	P188	A6	C10	152
I/O, V _{REF}	0	P189	B7	A9	155
V _{CCO}	0	-	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
GND	-	P190	GND*	GND*	-
I/O	0	P191	C8	B9	158
I/O	0	P192	D7	E10	161
I/O	0	-	-	C9	164
I/O	0	-	-	D10	167
I/O	0	P193	E7	A8	170
GND	-	-	GND*	GND*	-
I/O	0	-	-	D9	173
I/O	0	-	-	B8	176
I/O	0	-	-	C8	179
I/O	0	P194	C7	E9	182
I/O	0	P195	B6	A7	185
V _{CCINT}	-	P196	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	0	P197	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-

Additional XC2S200 Package Pins (Continued)

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FG456

V _{CCINT} Pins					
E5	E18	F6	F17	G7	G8
G9	G14	G15	G16	H7	H16
J7	J16	P7	P16	R7	R16
T7	T8	T9	T14	T15	T16
U6	U17	V5	V18	-	-
V _{CCO} Bank 0 Pins					
F7	F8	F9	F10	G10	G11
V _{CCO} Bank 1 Pins					
F13	F14	F15	F16	G12	G13
V _{CCO} Bank 2 Pins					
G17	H17	J17	K16	K17	L16
V _{CCO} Bank 3 Pins					
M16	N16	N17	P17	R17	T17
V _{CCO} Bank 4 Pins					
T12	T13	U13	U14	U15	U16
V _{CCO} Bank 5 Pins					
T10	T11	U7	U8	U9	U10
V _{CCO} Bank 6 Pins					
M7	N6	N7	P6	R6	T6
V _{CCO} Bank 7 Pins					

Additional XC2S200 Package Pins (Continued)

G6	H6	J6	K6	K7	L7
GND Pins					
A1	A22	B2	B21	C3	C20
J9	J10	J11	J12	J13	J14
K9	K10	K11	K12	K13	K14
L9	L10	L11	L12	L13	L14
M9	M10	M11	M12	M13	M14
N9	N10	N11	N12	N13	N14
P9	P10	P11	P12	P13	P14
Y3	Y20	AA2	AA21	AB1	AB22
Not Connected Pins					
A2	A6	A12	B11	B16	C2
D1	D4	D18	D19	E17	E19
G2	G22	L2	L19	M2	M21
R3	R20	U3	U18	V6	W4
W19	Y5	Y22	AA1	AA3	AA11
AA16	AB7	AB12	AB21	-	-

11/02/00

Revision History

Version No.	Date	Description
2.0	09/18/00	Sectioned the Spartan-II Family data sheet into four modules. Corrected all known errors in the pinout tables.
2.1	10/04/00	Added notes requiring $\overline{\text{PWDN}}$ to be tied to V _{CCINT} when unused.
2.2	11/02/00	Removed the Power Down feature.
2.3	03/05/01	Added notes on pinout tables for IRDY and TRDY.
2.4	04/30/01	Reinstated XC2S50 V _{CCO} Bank 7, GND, and "not connected" pins missing in version 2.3.
2.5	09/03/03	Added caution about Not Connected Pins to XC2S30 pinout tables on page 76 .
2.8	06/13/08	Added " Package Overview " section. Added notes to clarify shared V _{CCO} banks. Updated description and links. Updated all modules for continuous page, figure, and table numbering. Synchronized all modules to v2.8.